



### **Product Summary**

V <sub>(BR)DSS</sub>	R <sub>DS(ON)</sub> Max	I <sub>D</sub> Max T <sub>C</sub> = +25°C		
20V	12.5mΩ @ V <sub>GS</sub> = 4.5V	36A		
200	19mΩ @ V <sub>GS</sub> = 2.5V	30A		

### Description

This MOSFET is designed to minimize the on-state resistance  $(R_{DS(ON)})$ , yet maintain superior switching performance, making it ideal for high-efficiency power management applications.

# Applications

- Backlighting
- Power Management Functions
- DC-DC Converters

### 20V N-CHANNEL ENHANCEMENT MODE MOSFET

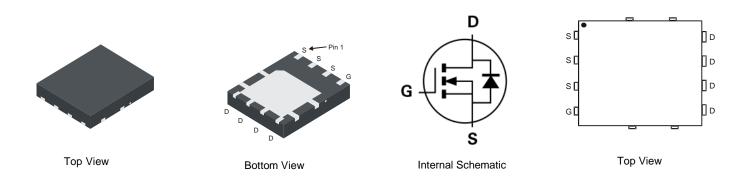
### **Features and Benefits**

- Low R<sub>DS(ON)</sub> Ensures On-State Losses Are Minimized
- Small Form Factor Thermally Efficient Package Enables Higher Density End Products
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- Qualified to AEC-Q101 standards for High Reliability

### **Mechanical Data**

- Case: POWERDI<sup>®</sup>5060-8
- Case Material: Molded Plastic, "Green" Molding Compound. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminal Connections: See Diagram Below
- Weight: 0.097 grams (Approximate)

#### POWERDI5060-8



# Ordering Information (Note 4)

Part Number	Case	Packaging
DMN2027UPS-13	POWERDI5060-8	2,500/Tape & Reel

Notes: 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant.

2. See http://www.diodes.com/quality/lead\_free.html for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.

3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.

4. For packaging details, go to our website at http://www.diodes.com/products/packages.html.



# **Marking Information**



) | | = Manufacturer's Marking N2027UP = Product Type Marking Code YYWW = Date Code Marking YY = Year (ex: 15 = 2015) WW = Week (01 - 53)

### Maximum Ratings (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Characteristic Drain-Source Voltage Gate-Source Voltage			Symbol	Value	Units V
			V <sub>DSS</sub>	20	
			V <sub>GSS</sub>	±12	V
Continuous Drain Current (Note 6) V <sub>GS</sub> = 4.5V	Steady State	T <sub>A</sub> = +25°C T <sub>A</sub> = +70°C	Ι <sub>D</sub>	10 8	А
	Steady State	T <sub>C</sub> = +25°C T <sub>C</sub> = +70°C	Ι <sub>D</sub>	36 29	A
Continuous Drain Current (Note 6) V <sub>GS</sub> = 2.5V	Steady State	T <sub>A</sub> = +25°C T <sub>A</sub> = +70°C	ID	8.2 6.6	A
	Steady State	T <sub>C</sub> = +25°C T <sub>C</sub> = +70°C	ID	30 23	A
Maximum Continuous Body Diode Forward Current (Infinite Heatsink)			Is	60	А
Pulsed Drain Current (380µs Pulse, Duty Cycle = 1%)			I <sub>DM</sub>	60	А
Avalanche Current (Note 7) L = 0.1mH			I <sub>AS</sub>	6.8	А
Avalanche Energy (Note 7) L = 0.1mH			E <sub>AS</sub>	2.3	mJ

### **Thermal Characteristics**

Characteristic	Symbol	Value	Units	
Total Power Dissipation (Note 5)	PD	1.1	W	
Thermal Resistance, Junction to Ambient (Note 5)	Steady State	D	112	°C/W
memai Resistance, Junction to Ambient (Note 5)	t<10s	R <sub>0JA</sub>	58	°C/W
Total Power Dissipation (Note 6)		PD	1.9	W
Thermal Resistance, Junction to Ambient (Note 6)	Steady State	Р	65	°C/W
Thermal Resistance, Junction to Ambient (Note 6)	t<10s	R <sub>θJA</sub>	34	°C/W
Thermal Resistance, Junction to Case	R <sub>θJC</sub>	5	°C/W	
Operating and Storage Temperature Range		T <sub>J.</sub> T <sub>STG</sub>	-55 to +150	°C

Notes: 5. Device mounted on FR-4 substrate PC board, 2oz copper, with minimum recommended pad layout.

6. Device mounted on FR-4 substrate PC board, 2oz copper, with 1-inch square copper plate.

7. I<sub>AS</sub> and E<sub>AS</sub> rating are based on low frequency and duty cycles to keep  $T_J$  = +25°C.



# Electrical Characteristics (@T<sub>A</sub> = +25°C, unless otherwise specified.)

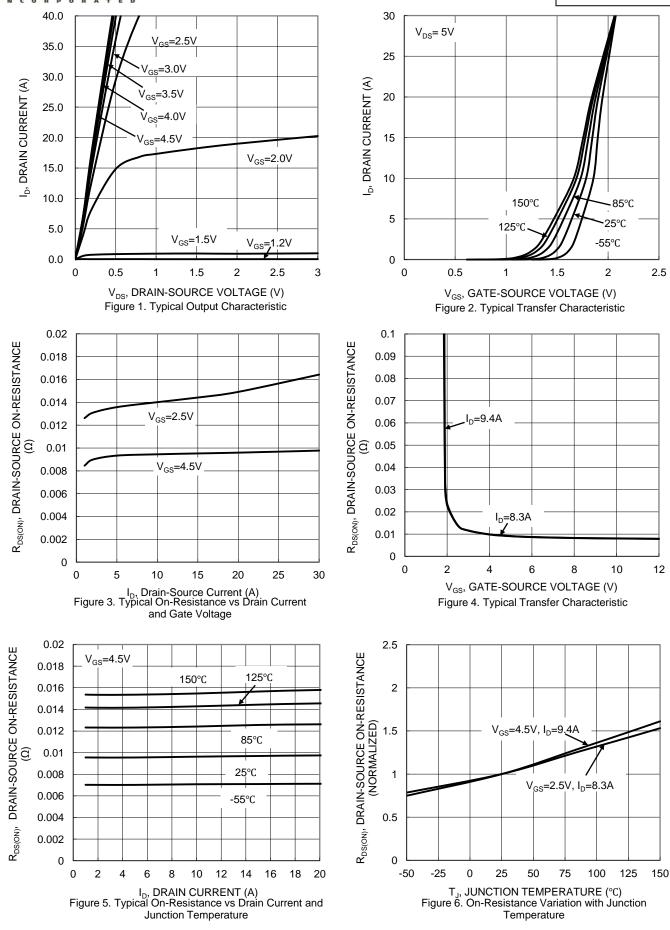
			_				
Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition	
OFF CHARACTERISTICS (Note 8)			1	1		I	
Drain-Source Breakdown Voltage	BV <sub>DSS</sub>	20	—	—	V	$V_{GS} = 0V, I_D = 250\mu A$	
Zero Gate Voltage Drain Current	IDSS	_	—	1.0	μA	$V_{DS} = 20V, V_{GS} = 0V$	
Gate-Source Leakage	I <sub>GSS</sub>	—		±100	nA	$V_{GS} = \pm 12V$ , $V_{DS} = 0V$	
ON CHARACTERISTICS (Note 8)							
Gate Threshold Voltage	V <sub>GS(TH)</sub>	0.7		1.3	V	$V_{DS} = V_{GS}$ , $I_D = 250 \mu A$	
Static Drain-Source On-Resistance	0		_	12.5	mΩ	$V_{GS} = 4.5V, I_D = 9.4A$	
Static Drain-Source On-Resistance	R <sub>DS(ON)</sub>		_	19	11152	V <sub>GS</sub> = 2.5V, I <sub>D</sub> = 8.3A	
Diode Forward Voltage	V <sub>SD</sub>	_	0.7	1.3	V	$V_{GS} = 0V, I_{S} = 1.3A$	
DYNAMIC CHARACTERISTICS (Note 9)							
Input Capacitance	Ciss		1091	—		$V_{DS} = 10V, V_{GS} = 0V,$ f = 1.0MHz	
Output Capacitance	C <sub>oss</sub>	_	163	_	pF		
Reverse Transfer Capacitance	Crss	_	148	_			
Gate Resistance	Rq	_	1.5	3.2	Ω	$V_{DS} = 0V, V_{GS} = 0V, f = 1MHz$	
Total Gate Charge (V <sub>GS</sub> = 2.5V)	Qq	_	7.0	_			
Total Gate Charge (V <sub>GS</sub> = 4.5V)	Qq	_	11.6	_	-0	$V_{DS} = 10V, I_D = 9.4A$	
Gate-Source Charge	Q <sub>gs</sub>		2.5	_	nC		
Gate-Drain Charge	Q <sub>qd</sub>	_	3.5	_			
Turn-On Delay Time	t <sub>D(ON)</sub>	_	6.6	_		$\label{eq:VGS} \begin{array}{l} V_{GS} = 4.5V,  V_{DS} = 10V, \\ R_{G} = 6\Omega \;,  I_{D} = 1A \end{array}$	
Turn-On Rise Time	t <sub>R</sub>		8.4	_			
Turn-Off Delay Time	t <sub>D(OFF)</sub>		26.6	—	nS		
Turn-Off Fall Time	t <sub>F</sub>	_	12.6	—	1		
Reverse Recovery Time	t <sub>RR</sub>		13.2	—	nS		
Reverse Recovery Charge	Q <sub>RR</sub>	_	7.6	_	nC	I <sub>F</sub> = 12A, di/dt = 500A/µs	

 Notes:
 8. Short duration pulse test used to minimize self-heating effect.

 9. Guaranteed by design. Not subject to product testing.

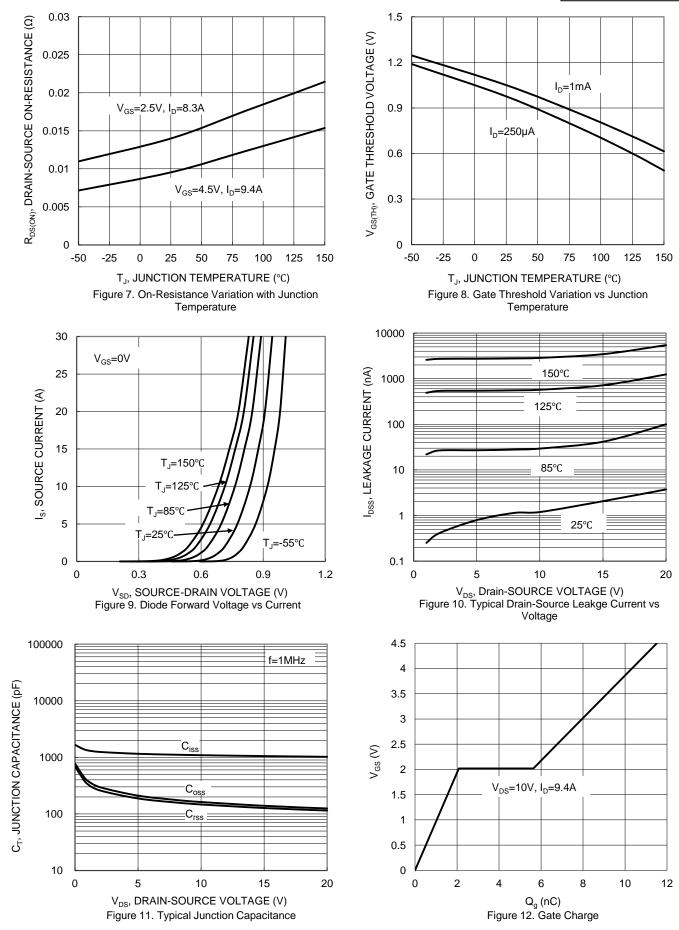


# DMN2027UPS





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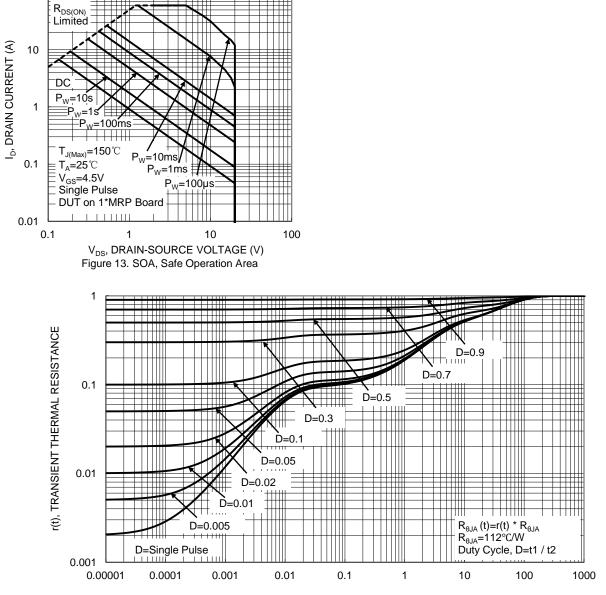


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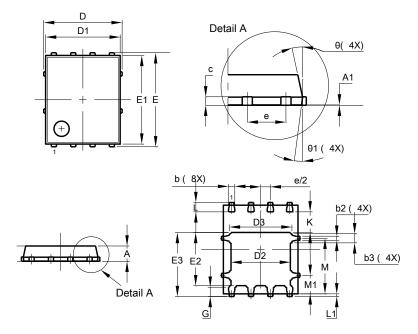
t1, PULSE DURATION TIME (sec) Figure 14 Transient Thermal Resistance



# **Package Outline Dimensions**

Please see AP02002 at http://www.diodes.com/datasheets/ap02002.pdf for the latest version.

#### POWERDI5060-8

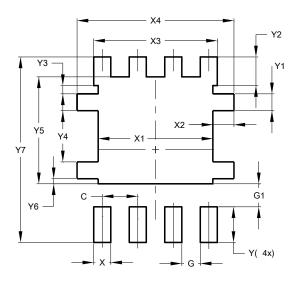


POWERDI5060-8					
Dim	Min	Max	Тур		
Α	0.90	1.10	1.00		
A1	0.00	0.05	_		
b	0.33	0.51	0.41		
b2	0.200	0.350	0.273		
b3	0.40	0.80	0.60		
С	0.230	0.330	0.277		
D		.15 BS	С		
D1	4.70	5.10	4.90		
D2	3.70	4.10	3.90		
D3	3.90	4.30	4.10		
E	6	.15 BS	C		
E1	5.60	6.00	5.80		
E2	3.28	3.68	3.48		
E3	3.99	4.39	4.19		
е	1.27 BSC				
G	0.51	0.71	0.61		
K	0.51	—	—		
L	0.51	0.71	0.61		
L1	0.100	0.200	0.175		
М	3.235	4.035	3.635		
M1	1.00	1.40	1.21		
θ	10°	12°	11°		
θ1	6°	8°	7°		
All Dim	All Dimensions in mm				

# Suggested Pad Layout

Please see AP02001 at http://www.diodes.com/datasheets/ap02001.pdf for the latest version.

#### POWERDI5060-8



Dimensions	Value (in mm)
С	1.270
G	0.660
G1	0.820
Х	0.610
X1	4.100
X2	0.755
X3	4.420
X4	5.610
Y	1.270
Y1	0.600
Y2	1.020
Y3	0.295
Y4	1.825
Y5	3.810
Y6	0.180
Y7	6.610



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